TPS568215OA 4.5V 至 17V 输入、8A 同步降压 SWIFT™ 转换器

1 特性

- 集成 19mΩ 和 9.4mΩ 金属氧化物半导体场效应晶体管 (MOSFET)
- 400kHz、800kHz 或 1.2MHz 的可选 F_{SW}
- Out-of-Audio 功能可保持开关频率超出音频范围
- 可调节电流限制设置，具有断续重启功能
- 整个温度范围内的基准电压为 0.6V ±1%
- 支持 5V 外部可选偏置功能，以提升效率
- D-CAP3™针对快速瞬态响应的控制模式
- 0.6V 至 5.5V 输出电压范围
- 支持所有陶瓷电容器
- 针对预偏置输出的单调性启动
- 可调节软启动，默认软启动时间为 1ms
- -40°C 至 150°C 运行结温
- 小型 3.5mm x 3.5mm HotRod™四方扁平无引线 (QFN) 封装

2 应用

- 服务器和存储
- 机顶盒和高端数字电视 (DTV)
- 笔记本电脑和游戏系统

3 说明

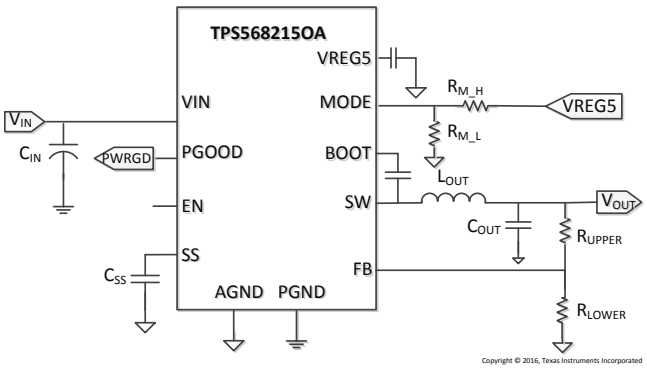
TPS568215OA 是 TI 旗下最小的一款单片 8A 同步降压转换器，具有自适应导通时间 D-CAP3™ 控制模式。该器件集成了较低的 $R_{DS(on)}$ 功率 MOSFET，简单易用并且高效运行，所需外部组件最少，适用于空间受限的电源系统。主要 特性 包括非常精确的基准电压、快速负载瞬态响应、Out-of-Audio 模式、可调节的电流限制并且无需外部补偿。强制持续导通模式有助于满足高性能 DSP 和 FPGA 的严格电压调节精度要求。TPS568215OA 采用热增强型 18 引脚 HotRod™ QFN 封装，并且设计用于在 –40°C 至 150°C 的结温范围内工作。TPS568215OA 与 TPS568215 和 TPS56C215 引脚对引脚兼容，因此用户可以在 6A 至 12A 范围内灵活选择采用同一大小的解决方案。

器件信息(1)

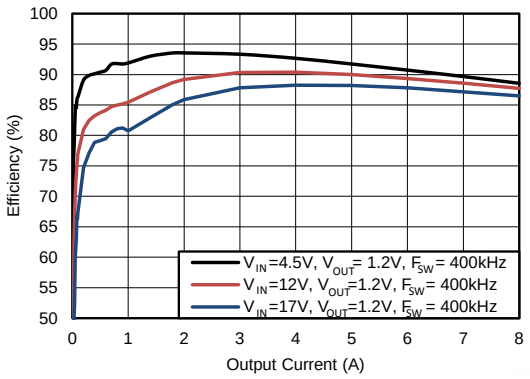
器件型号	封装	封装尺寸（标称值）
TPS568215OA	VQFN (18)	3.50mm x 3.50mm

(1) 如需了解所有可用封装，请参阅产品说明书末尾的可订购产品附录。

典型应用原理图



效率与输出电流



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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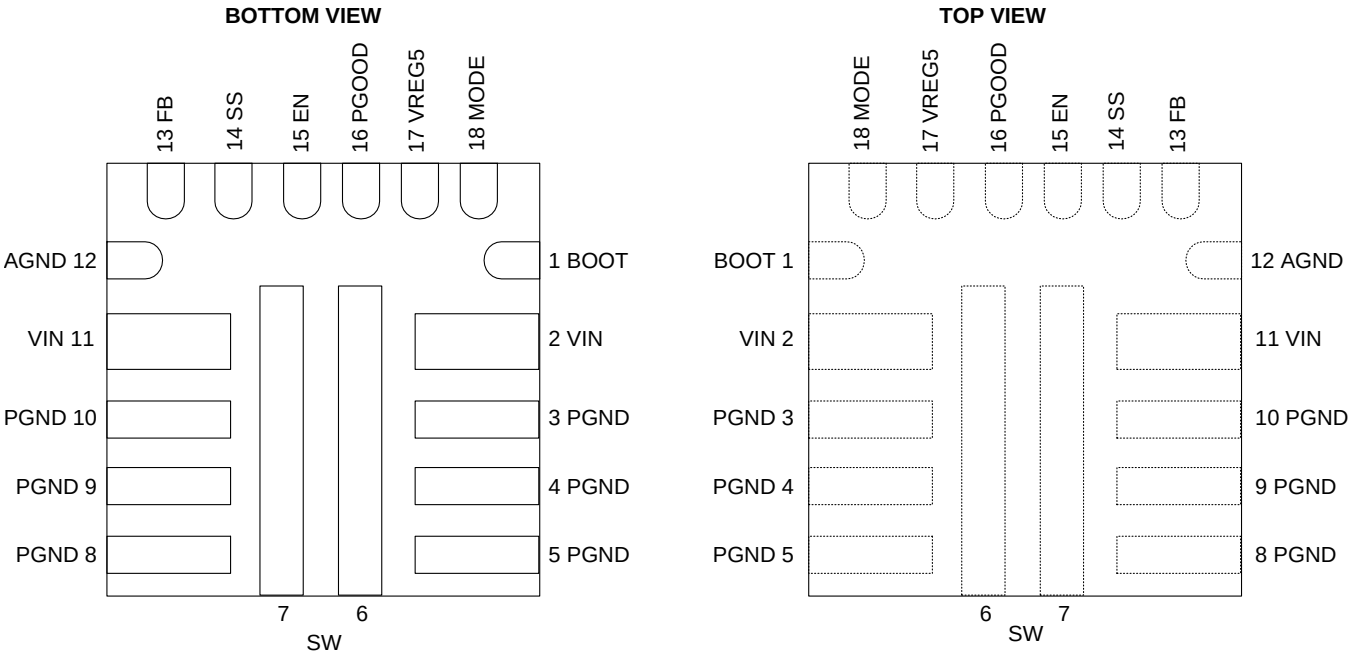
4 修订历史记录

日期	修订版本	注释
2017 年 1 月	*	初始发行版。

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5 Pin Configuration and Functions

RNN Package
18-Pin VQFN



Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	BOOT	I	Supply input for the gate drive voltage of the high-side MOSFET. Connect a 0.1-µF bootstrap capacitor between BOOT and SW.
2,11	VIN	P	Input voltage supply pin for the control circuitry. Connect the input decoupling capacitors between VIN and PGND.
3, 4, 5, 8, 9, 10	PGND	G	Power GND terminal for the controller circuit and the internal circuitry.
6, 7	SW	O	Switch node terminal. Connect the output inductor to this pin.
12	AGND	G	Ground of internal analog circuitry. Connect AGND to PGND plane.
13	FB	I	Converter feedback input. Connect to the resistor divider between output voltage and AGND.
14	SS	O	Soft-Start time selection pin. Connecting an external capacitor sets the soft-start time and if no external capacitor is connected, the soft-start time in 1ms.
15	EN	I	Enable input control, leaving this pin floating enables the converter. It can also be used to adjust the input UVLO by connecting to the resistor divider between VIN and EN.
16	PGOOD	O	Open Drain Power Good Indicator, it is asserted low if output voltage is out of PGOOD threshold, Overvoltage or if the device is under thermal shutdown, EN shutdown or during soft start.
17	VREG5	I/O	4.7-V internal LDO output which can also be driven externally with a 5V input. This pin supplies voltage to the internal circuitry and gate driver. Bypass this pin with a 4.7-µF capacitor.
18	MODE	I	Switching Frequency, Current Limit selection and Light load operation mode selection pin. Connect this pin to a resistor divider from VREG5 and AGND for different MODE options shown in table 4.

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Input Voltage	VIN	–0.3	20	V
	SW	–2	19	
	SW(10 ns transient)	–3	20	
	EN	–0.3	6.5	
	BOOT –SW	–0.3	6.5	
	BOOT	–0.3	25.5	
	SS, MODE, FB	–0.3	6.5	
	VREG5	–0.3	6	
Output Voltage	PGOOD	–0.3	6.5	V
Output Current, I_{OUT} (2)			10	A
Operating junction temperature, T_J		–40	150	°C
Storage temperature, T_{stg}		–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) In order to be consistent with the TI reliability requirement of 100k continuos Power-On-Hours with 105°C junction temperature at the max output current of 10A, the converter's duty cycle should be limited to 60% operation as to prevent electromigration failure in the solder. If higher duty cycle is required at 10A load the total power on hours or the junction temperature have to be reduced.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Input Voltage	V_{IN}	4.5		17	V
	SW	–1.8		17	
	BOOT	–0.1		23.5	
	VREG5	–0.1		5.2	
T_J	Operating junction temperature	-40		150	°C

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6.4 Thermal Information

THERMAL METRIC(1)		TPS568215OA RNN (VQFN) 18 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	42.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	23.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	10.0	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	10.0	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	0.5	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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6.5 Electrical Characteristics

T_J = –40°C to 150°C, VIN=12V (unless otherwise noted)

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I_{IN}	V_{IN} supply current	T_J = 25°C, V_{EN}=5 V, non switching		850		µA
I_{VINSDN}	V_{IN} shutdown current	T_J = 25°C, V_{EN}=0 V		7		µA
LOGIC THRESHOLD						
V_{ENH}	EN H-level threshold voltage		1.175	1.225	1.3	V
V_{ENL}	EN L-level threshold voltage		1.025	1.104	1.15	V
V_{ENHYS}				0.121		V
I_{ENp1}	EN pull-up current	V_{EN} = 1.0 V	0.35	1.91	2.95	µA
I_{ENp2}		V_{EN} = 1.3 V	3	4.197	5.5	µA
FEEDBACK VOLTAGE						
V_{FB}	FB voltage	T_J = 25°C	598	600	602	mV
		T_J = 0°C to 85°C	597.5	600	602.5	mV
		T_J = –40°C to 85°C	594	600	602.5	mV
		T_J = –40°C to 150°C	594	600	606	mV
LDO VOLTAGE						
VREG5	LDO Output voltage	T_J = –40°C to 150°C	4.58	4.7	4.83	V
ILIM5	LDO Output Current limit	T_J = –40°C to 150°C	100	150	200	mA
MOSFET						
$R_{DS(on)H}$	High side switch resistance	T_J = 25°C, V_{VREG5} = 4.7 V		19		mΩ
$R_{DS(on)L}$	Low side switch resistance	T_J = 25°C, V_{VREG5} = 4.7 V		9.4		mΩ
SOFT START						
I_{ss}	Soft start charge current	T_J = -40°C to 150°C	4.9	6	7.1	µA
CURRENT LIMIT						
I_{OCL}	Current Limit (Low side sourcing)	ILIM-1 option, Valley Current	6	7.1	8.15	A
		ILIM option, Valley Current	8	9.4	10.8	A
		ILIM+1 option, Valley Current	10	11.8	13.5	A
	Current Limit (Low side negative)	Valley Current		3		A
POWER GOOD						
$V_{PGOODTH}$	PGOOD threshold	V_{FB} falling (fault)		84%		%V_{REF}
		V_{FB} rising (good)		93%		%V_{REF}
		V_{FB} rising (fault)		116%		%V_{REF}
		V_{FB} falling (good)		107%		%V_{REF}
OUTPUT UNDERVOLTAGE PROTECTION						
V_{UVP}	Output UVP threshold	Hiccup detect		68% x V_{FB}		
THERMAL SHUTDOWN						
T_{SDN}	Thermal shutdown threshold	Shutdown temperature		160		°C
		Hysteresis		15		°C
$T_{SDN\ VREG5}$	VREG5 thermal shutdown threshold	Shutdown temperature		171		°C
		Hysteresis		18		°C
UVLO						
UVLO	UVLO threshold	VREG5 rising voltage	4.1	4.3	4.5	V
		VREG5 falling voltage	3.34	3.57	3.8	V
		VREG5 hysteresis		730		mV

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6.6 Timing Requirements

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT
ON-TIME TIMER CONTROL						
t_{ON}	SW On Time	V_{IN} = 12 V, V_{OUT}=3.3 V, F_{SW} = 800 kHz	310	340	380	ns
$t_{ON\ min}$	SW Minimum on time	V_{IN} = 17 V, V_{OUT}=0.6 V, F_{SW}= 1200 kHz		54		ns
t_{OFF}	SW Minimum off time	25°C, V_{FB}=0.5 V			310	ns
F_{SWOOA}	OOA Switching Frequency	T_J = -40°C to 150°C, No Load	20		27	KHz
SOFT START						
t_{SS}	Soft start time	Internal soft start time		1.045		ms
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
t_{UVPDEL}	Output Hiccup delay relative to SS time	UVP detect		1		cycle
t_{UVPEN}	Output Hiccup enable delay relative to SS time	UVP detect		7		cycle

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6.7 Typical Characteristics

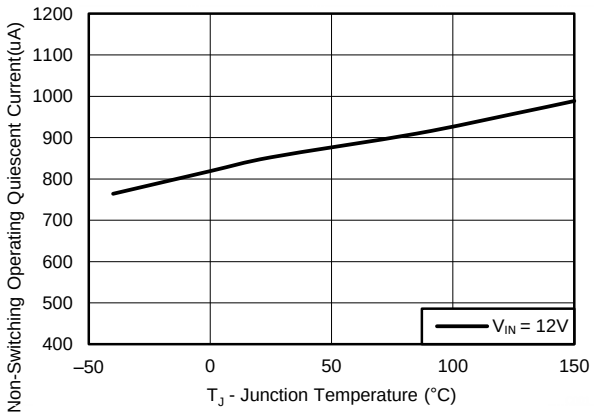


图 1. Quiescent Current vs Temperature

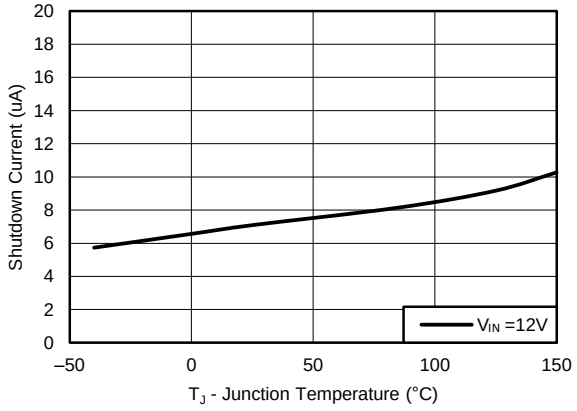


图 2. Shutdown Current vs Temperature

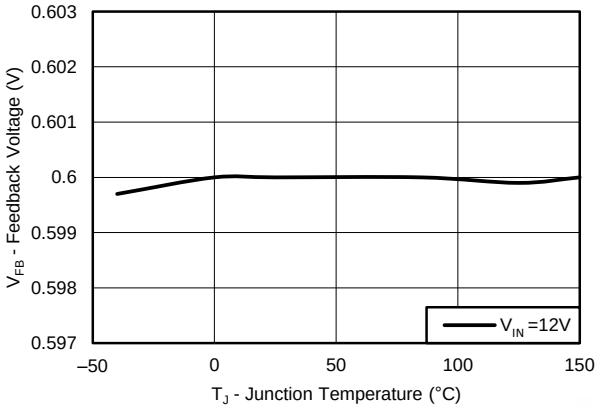


图 3. Feedback Voltage vs Temperature

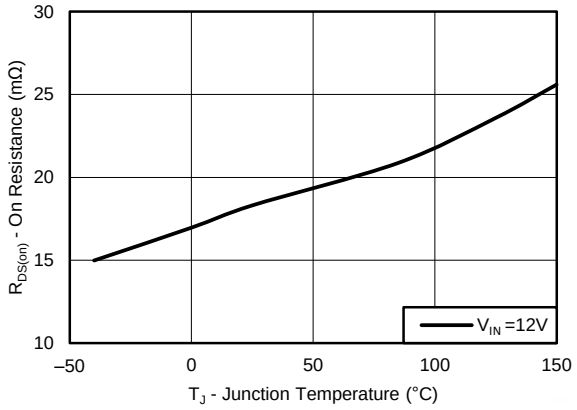


图 4. High-side R_{dson} vs Temperature

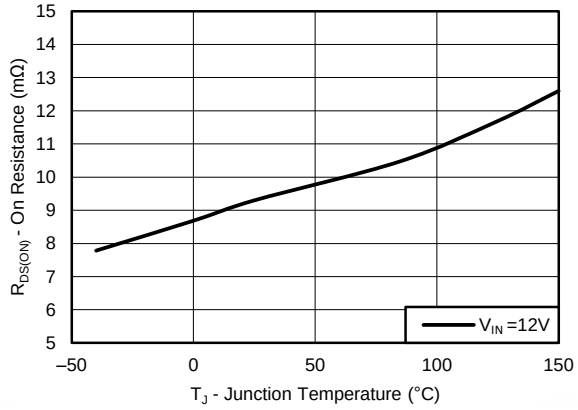


图 5. Low-side R_{dson} vs Temperature

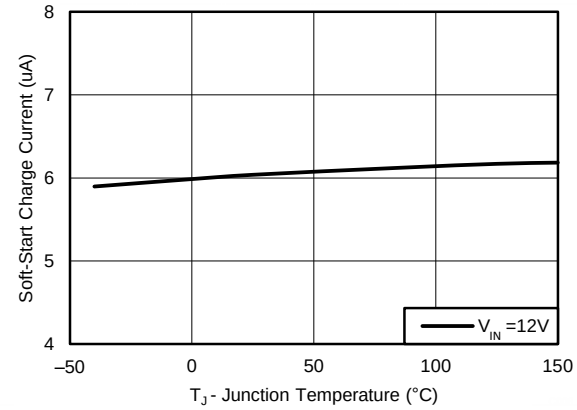


图 6. Soft-Start Charge Current vs Temperature

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Typical Characteristics (接下页)

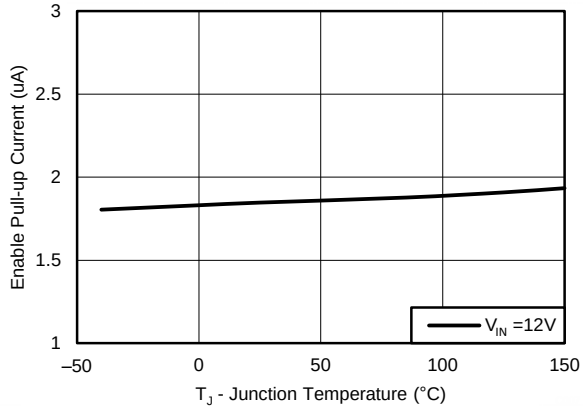


图 7. Enable Pull-Up Current, V_{EN} =1.0V

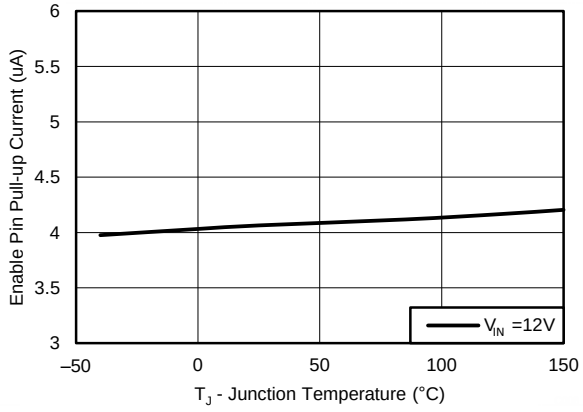


图 8. Enable Pull-Up Current, V_{EN} =1.3V

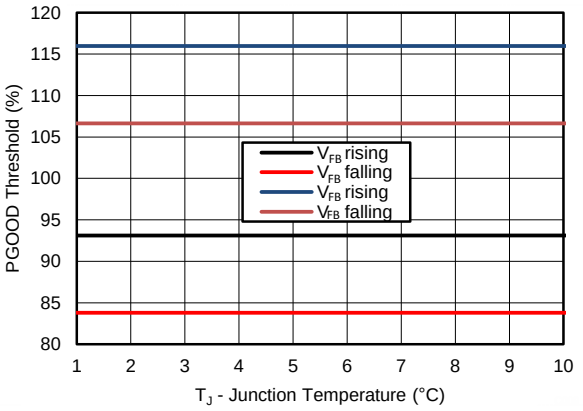


图 9. PGOOD Threshold vs Temperature

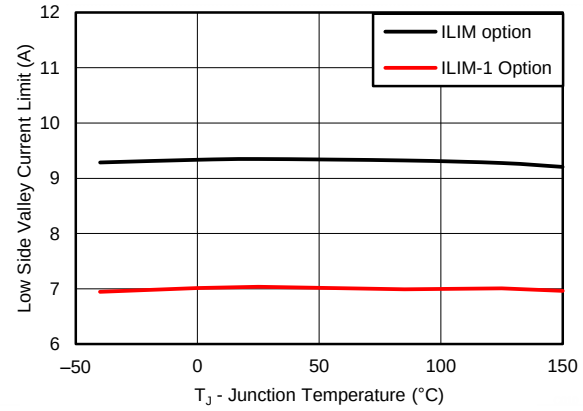


图 10. Valley Current Limit vs Temperature

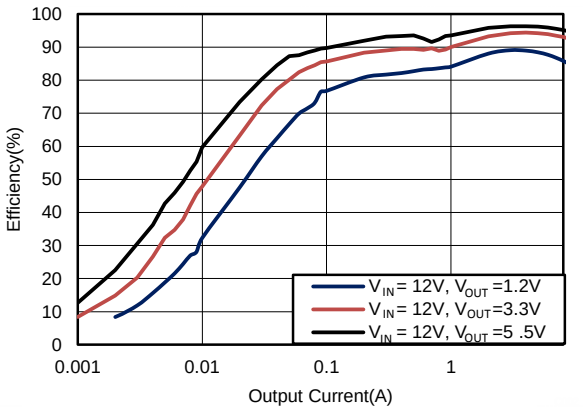


图 11. Efficiency, Mode = OOA, F_{SW} = 400kHz

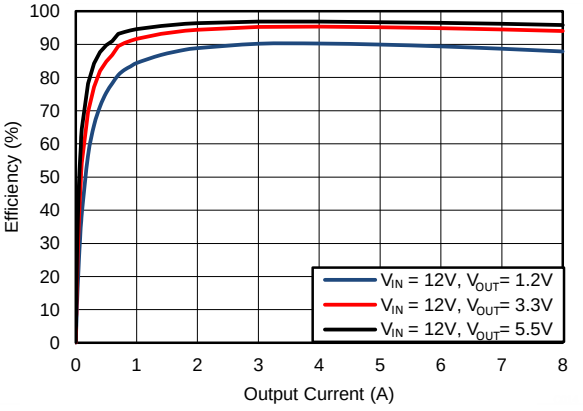


图 12. Efficiency, Mode = FCCM, F_{SW} = 400kHz

Typical Characteristics (接下页)

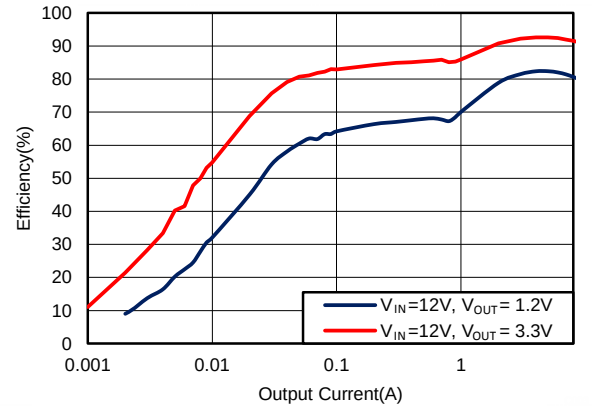


图 13. Efficiency, Mode = OOA, F_{SW} = 1200kHz

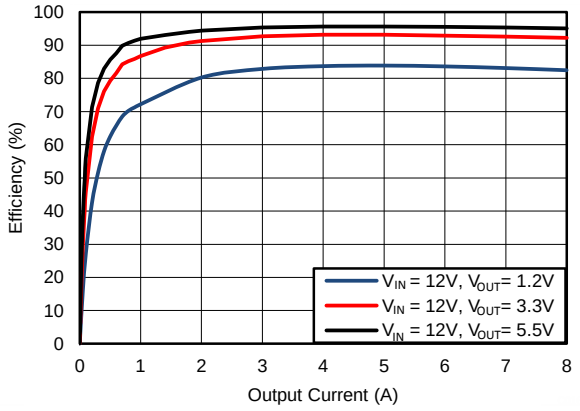


图 14. Efficiency, Mode = FCCM, F_{SW} = 1200kHz

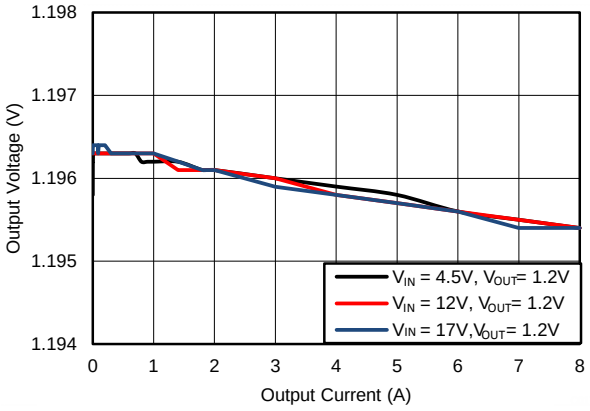


图 15. Load Regulation, F_{SW} = 400kHz

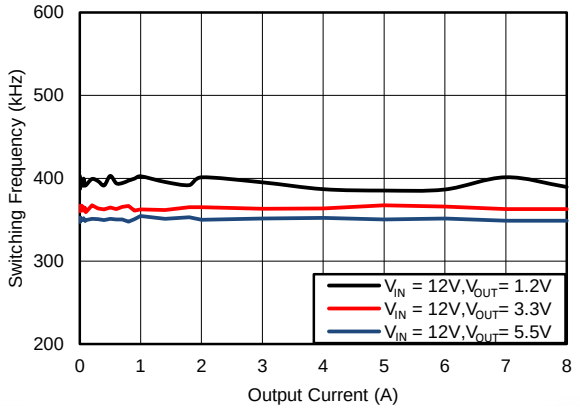


图 16. F_{SW} Load Regulation, Mode = FCCM, F_{SW} = 400kHz

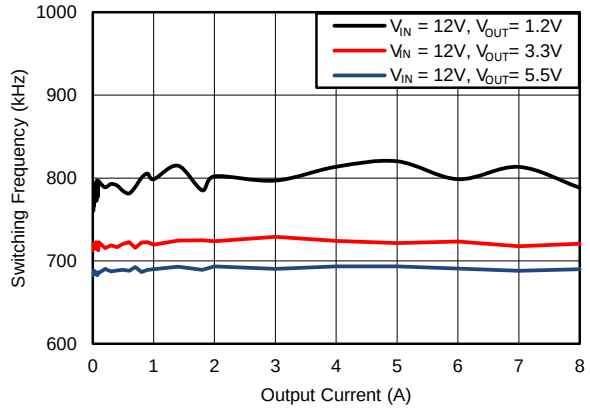


图 17. F_{SW} Load Regulation, Mode = FCCM, F_{SW} = 800kHz

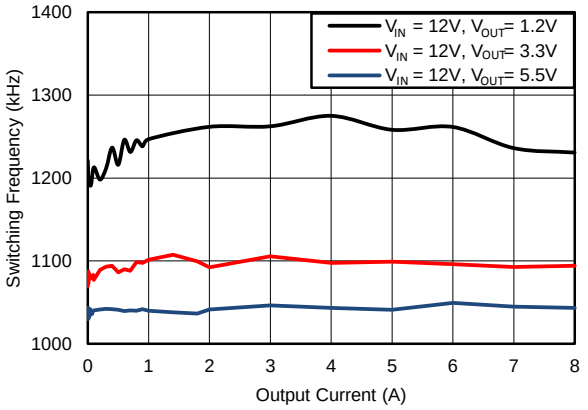


图 18. F_{SW} Load Regulation, Mode = FCCM, F_{SW} = 1200kHz

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Typical Characteristics (接下页)

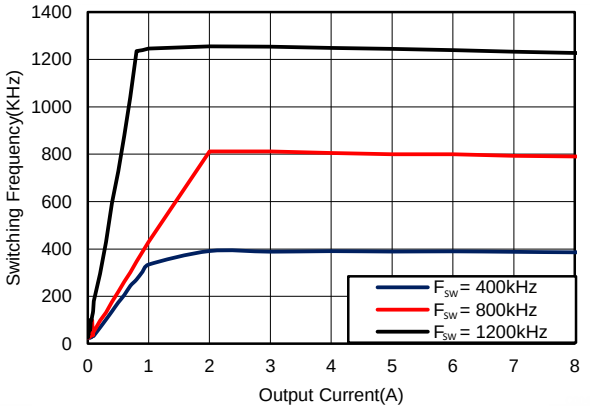


图 19. F_{SW} Load Regulation, Mode = OOA, V_{IN} = 12V, V_{OUT}=1.2V

7 Detailed Description

7.1 Overview

The TPS568215OA is a high density synchronous step down buck converter which can operate from 4.5-V to 17-V input voltage (V_{IN}). It has 19-mΩ and 9-mΩ integrated MOSFETs that enable high efficiency up to 10 A. The device employs D-CAP3™ mode control that provides fast transient response with no external compensation components and an accurate feedback voltage. The control topology provides seamless transition between FCCM operating mode at higher load condition and OOA operation at lighter load condition. OOA feature allows the TPS568215OA to keep switching frequency above the audible frequency range. The TPS568215OA is able to adapt to both low equivalent series resistance (ESR) output capacitors such as POSCAP or SP-CAP, and ultralow ESR ceramic capacitors.

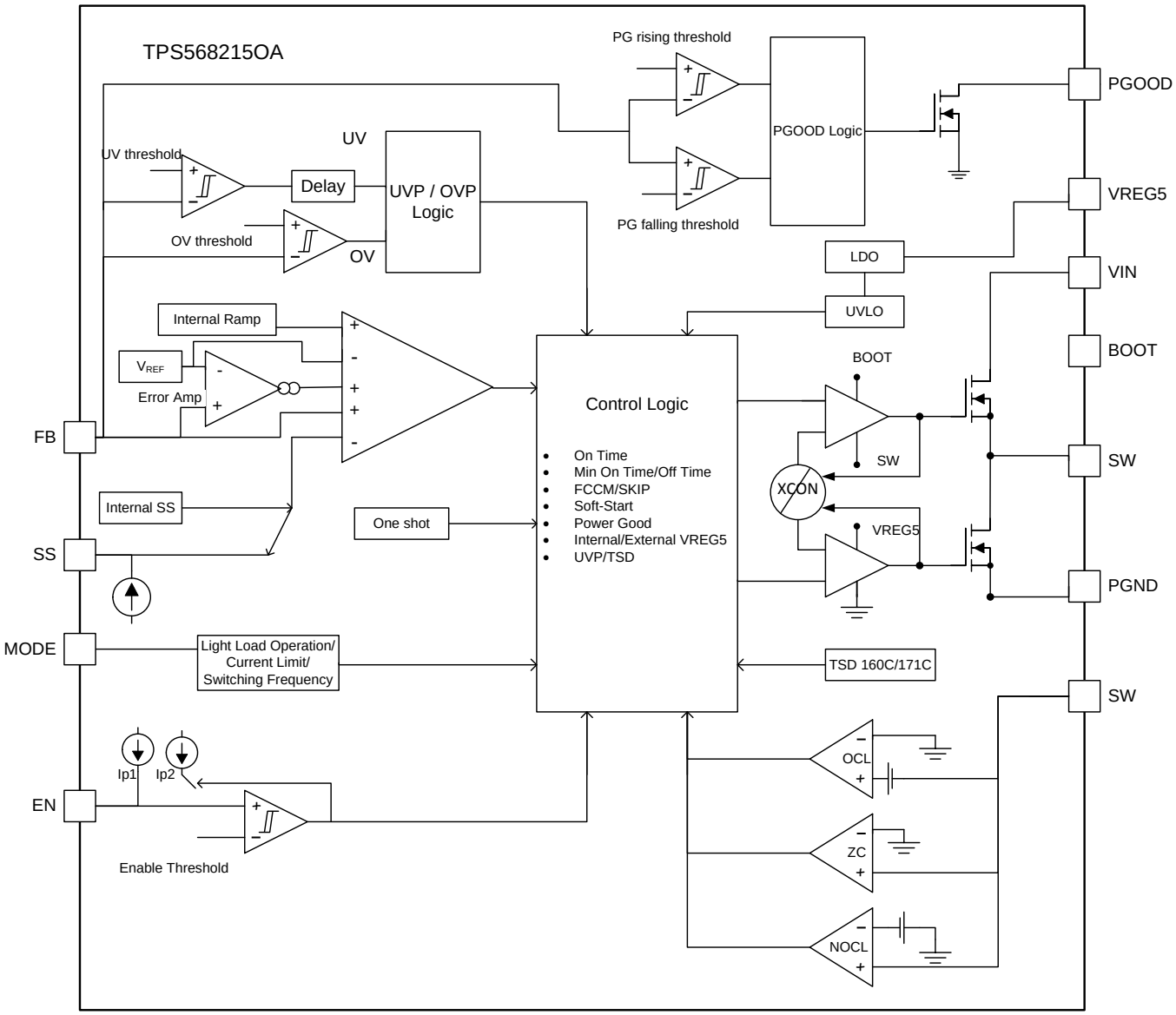
The TPS568215OA has three selectable switching frequencies (F_{SW}) 400kHz, 800kHz and 1200kHz which gives the flexibility to optimize the design for higher efficiency or smaller size. There are three selectable current limits. All these options are configured by choosing the right voltage on the MODE pin.

The TPS568215OA has a 4.7 V internal LDO that creates bias for all internal circuitry. There is a feature to overdrive this internal LDO with an external voltage on the VREG5 pin which improves the converter's efficiency. The undervoltage lockout (UVLO) circuit monitors the VREG5 pin voltage to protect the internal circuitry from low input voltages. The device has an internal pull-up current source on the EN pin which can enable the device even with the pin floating.

Soft-start time can be selected by connecting a capacitor to the SS pin. The device is protected from output short, undervoltage and over temperature conditions.

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7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 PWM Operation and D-CAP3™ Control

The TPS568215OA operates using the adaptive on-time PWM control with a proprietary D-CAP3™ control which enables low external component count with a fast load transient response while maintaining a good output voltage accuracy. At the beginning of each switching cycle the high side MOSFET is turned on for an on-time set by an internal one shot timer. This on-time is set based on the converter's input voltage, output voltage and the pseudo-fixed frequency hence this type of control topology is called an adaptive on-time control. The one shot timer resets and turns on again once the feedback voltage (V_{FB}) falls below the internal reference voltage (V_{REF}). An internal ramp is generated which is fed to the FB pin to simulate the output voltage ripple. This enables the use of very low-ESR output capacitors such as multi-layered ceramic caps (MLCC). No external current sense network or loop compensation is required for DCAP3™ control topology.

The TPS568215OA includes an error amplifier that makes the output voltage very accurate. This error amplifier is absent in other flavors of DCAP3™. For any control topology that is compensated internally, there is a range of the output filter it can support. The output filter used with the TPS568215OA is a low pass L-C circuit. This L-C filter has double pole that is described in

$$f_P = \frac{1}{2 \times \pi \times \sqrt{L_{OUT} \times C_{OUT}}} \quad (1)$$

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the TPS568215OA. The low frequency L-C double pole has a 180 degree in phase. At the output filter frequency, the gain rolls off at a –40dB per decade rate and the phase drops rapidly. The internal ripple generation network introduces a high-frequency zero that reduces the gain roll off from –40dB to –20dB per decade and increases the phase to 90 degree one decade above the zero frequency. The internal ripple injection high frequency zero is changed according to the switching frequency selected as shown in table below. The inductor and capacitor selected for the output filter must be such that the double pole is located close enough to the high-frequency zero so that the phase boost provided by this high-frequency zero provides adequate phase margin for the stability requirement. The crossover frequency of the overall system should usually be targeted to be less than one-fifth of the switching frequency (F_{SW}).

表 1. Ripple Injection Zero

SWITCHING FREQUENCY (kHz)	ZERO LOCATION (kHz)
400	7.1
800	14.3
1200	21.4

表 2 lists the inductor values and part numbers that are used to plot the efficiency curves in the *Typical Characteristics* section.

表 2. Inductor Values

V_{OUT}(V)	F_{SW}(kHz)	L_{OUT}(uH)	Würth PART NUMBER(1)
1.2	400	1.2	744325120
	800	0.68	744311068
	1200	0.47	744314047
3.3	400	2.4	744325240
	800	1.5	744314150
	1200	1.1	744314110
5.5	400	3.3	744325330
	800	2.4	744325240
	1200	1.2	744325120

(1) See *Third-Party Products* disclaimer

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7.3.2 Out-of-Audio Operation™

The TPS568215OA is designed with OOA feature that keeps switching frequency above the audible frequency region at light load or no load conditions. Once the converter determines that there is no switching for longer than 40us, it turns on the LS FET which brings V_{FB} lower than internal V_{REF} and initiates a new Ton cycle. This ensures that the switching frequency doesn't go lower than 25kHz typical.

7.3.3 4.7 V LDO and External Bias

The VREG5 pin is the output of the internal 4.7-V linear regulator that creates the bias for all the internal circuitry and MOSFET gate drivers. The VREG5 pin needs to be bypassed with a 4.7-µF capacitor. An external voltage that is above the LDO's internal output voltage can override the internal LDO, switching it to the external rail once a higher voltage is detected. This enhances the efficiency of the converter because the quiescent current now runs off this external rail instead of the input power supply. The UVLO circuit monitors the VREG5 pin voltage and disables the output when VREG5 falls below the UVLO threshold. When using an external bias on the VREG5 rail, any power-up and power-down sequencing can be applied but it is important to understand that if there is a discharge path on the VREG5 rail that can pull a current higher than the internal LDO's current limit (ILIM5) from the VREG5, then the VREG5 LDO turns off thereby shutting down the output of TPS568215OA. If such condition does not exist and if the external VREG5 rail is turned off, the VREG5 voltage switches over to the internal LDO voltage which is 4.7 V typically in a few nanoseconds. Figure 26 below shows this transition of the VREG5 voltage from an external bias of 5.5 V to the internal LDO output of 4.7 V when the external bias to VREG5 is disabled while the output of TPS568215OA remains unchanged.

7.3.4 MODE Selection

TPS568215OA has a MODE pin that can offer 16 different states of operation as a combination of Current Limit, Switching Frequency and Light Load operation. The device can operate at three different current limits ILIM-1,ILIM and ILIM+1 to support an output continuous current of 6 A, 8 A and 10A respectively. the device can provide 10A output current only at switching frequencies of 400kHz and 800kHz.The TPS568215OA is designed to compare the valley current of the inductor against the current limit thresholds so it is important to understand that the output current will be half the ripple current above the valley current. TPS568215OA can operate at three different frequencies of 400 kHz, 800 kHz and 1200 kHz and also can choose between OOA and FCCM mode. The device reads the voltage on the MODE pin during start-up and latches onto one of the MODE options listed below in table 3. The voltage on the MODE pin can be set by connecting this pin to the center tap of a resistor divider connected between VREG5 and AGND. A guideline for the top resistor (R_{M_H}) and the bottom resistor (R_{M_L}) as 5% resistors is shown in Table 3. It is important that the voltage for the MODE pin is derived from the VREG5 rail only since internally this voltage is referenced to detect the MODE option. The MODE pin setting can be reset only by a VIN power cycling.

表 3. Mode Pin Resistor Settings

R_{M_L} (kΩ)	R_{M_H} (kΩ)	LIGHT LOAD OPERATION	CURRENT LIMIT	FREQUENCY (kHz)
5.1	300	FCCM	ILIM-1	400
10	200	FCCM	ILIM	400
20	240	FCCM	ILIM+1	400
20	160	FCCM	ILIM-1	800
20	120	FCCM	ILIM	800
51	240	FCCM	ILIM+1	800
51	200	FCCM	ILIM-1	1200
51	180	FCCM	ILIM	1200
51	150	OOA	ILIM-1	400
51	120	OOA	ILIM	400
51	110	OOA	ILIM+1	400
51	91	OOA	ILIM-1	800
51	82	OOA	ILIM	800
51	75	OOA	ILIM+1	800
51	62	OOA	ILIM-1	1200
51	51	OOA	ILIM	1200

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图 20 below shows the typical start-up sequence of the device once the enable signal crosses the EN turn-on threshold. After the voltage on VREG5 crosses the rising UVLO threshold it takes about 500us to read the first mode setting and approximately 100us from there to finish the last mode setting. The output voltage starts ramping after the mode reading is done.

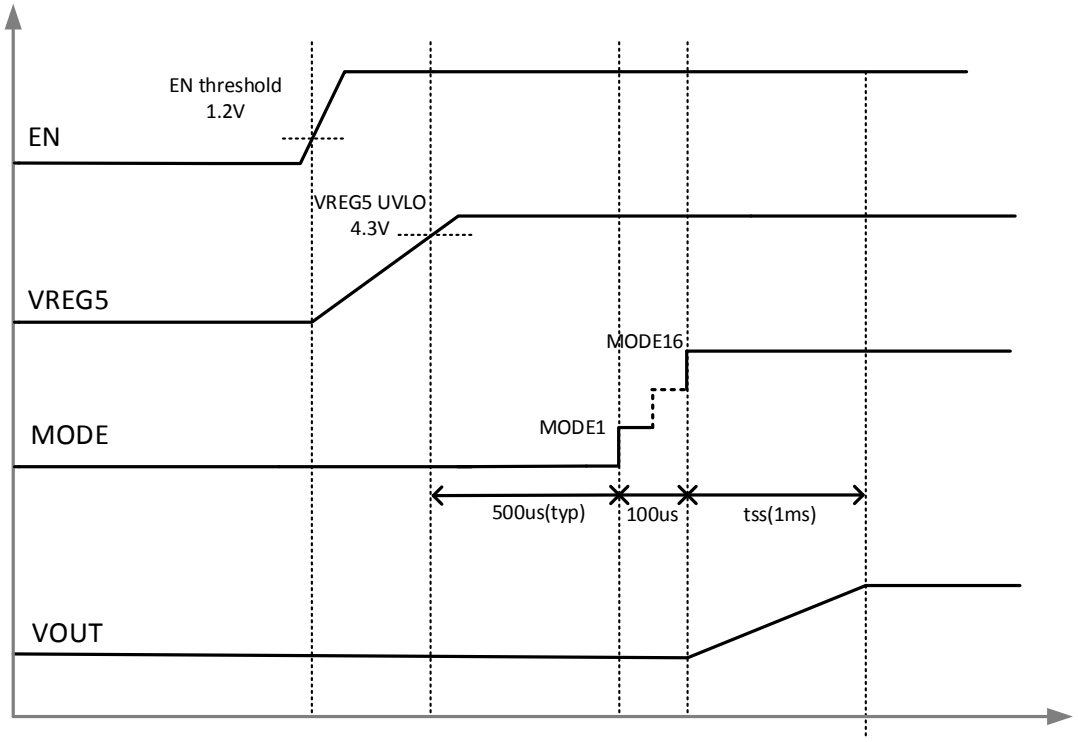


图 20. Power-Up Sequence

7.3.5 Soft Start and Pre-biased Soft Start

The TPS568215OA has an adjustable soft-start time that can be set by connecting a capacitor on SS pin. When the EN pin becomes high, the soft-start charge current (I_{SS}) begins charging the external capacitor (C_{SS}) connected between SS and AGND. The devices tracks the lower of the internal soft-start voltage or the external soft-start voltage as the reference. The equation for the soft-start time (T_{SS}) is shown in 公式 2:

$$T_{SS(S)} = \frac{C_{SS} \times V_{REF}}{I_{SS}} \quad (2)$$

where

- V_{REF} is 0.6 V and I_{SS} is 6 µA

If the output capacitor is pre-biased at startup, the device initiates switching and starts ramping up only after the internal reference voltage becomes greater than the feedback voltage V_{FB}. This scheme ensures that the converters ramp up smoothly into regulation point.

7.3.6 Enable and Adjustable UVLO

The EN pin controls the turn-on and turn-off of the device. When EN pin voltage is above the turn-on threshold which is around 1.2 V, the device starts switching and when the EN pin voltage falls below the turn-off threshold which is around 1.1V it stops switching. If the user application requires a different turn-on (V_{START}) and turn-off thresholds (V_{STOP}) respectively, the EN pin can be configured as shown in 图 21 by connecting a resistor divider between VIN and EN. The EN pin has a pull-up current I_{p1} that sets the default state of the pin when it is floating. This current increases to I_{p2} when the EN pin voltage crosses the turn-on threshold. The UVLO thresholds can be set by using 公式 3 and 公式 4.

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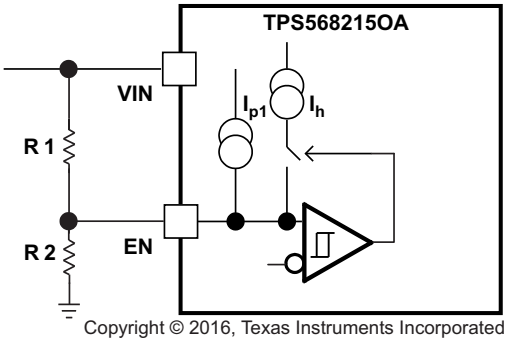


图 21. Adjustable VIN Under Voltage Lock Out

$$R1 = \frac{V_{START}\left(\frac{V_{ENFALLING}}{V_{ENRISING}}\right) - V_{STOP}}{I_{p1}\left(1 - \frac{V_{ENFALLING}}{V_{ENRISING}}\right) + I_h} \quad (3)$$

$$R2 = \frac{R1 \times V_{ENFALLING}}{V_{STOP} - V_{ENFALLING} + R1\ I_{p2}}$$

where

- I_{p2} = 4.197 μA
- I_{p1} = 1.91 μA
- I_h = 2.287 μA
- $V_{ENRISING}$ = 1.225 V
- $V_{ENFALLING}$ = 1.104 V (4)

7.3.7 Power Good

The Power Good (PGOOD) pin is an open drain output. Once the FB pin voltage is between 93% and 107% of the internal reference voltage (V_{REF}) the PGOOD is de-asserted and floats after a 200 μs de-glitch time. A pull-up resistor of 10 kΩ is recommended to pull it up to VREG5. The PGOOD pin is pulled low when the FB pin voltage is lower than V_{UVP} or greater than V_{OVP} threshold; or, in an event of thermal shutdown or during the soft-start period.

7.3.8 Over Current Protection and Under Voltage Protection

The output overcurrent limit (OCL) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored during the OFF state by measuring the low-side FET drain to source voltage. This voltage is proportional to the switch current. During the on time of the high-side FET switch, the switch current increases at a linear rate determined by input voltage , output voltage, the on-time and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current I_{OUT}. If the measured drain to source voltage of the low-side FET is above the voltage proportional to current limit, the low side FET stays on until the current level becomes lower than the OCL level which reduces the output current available. When the current is limited the output voltage tends to drop because the load demand is higher than what the converter can support. When the output voltage falls below 68% of the target voltage, the UVP comparator detects it and shuts down the device after a wait time of 1ms, the device re-starts after a hiccup time of 7ms. In this type of valley detect control the load current is higher than the OCL threshold by one half of the peak to peak inductor ripple current. When the overcurrent condition is removed, the output voltage returns to the regulated value. If an OCL condition happens during start-up then the device enters hiccup-mode immediately without a wait time of 1ms.

7.3.9 Out-of-Bounds Operation

The device has an out-of-bounds (OOB) overvoltage protection that protects the output load at a much lower overvoltage threshold of 8% above the target voltage. OOB protection does not trigger an overvoltage fault, OOB protection operates as an early no-fault overvoltage protection mechanism. During the OOB operation, the controller operates in forced PWM mode only by turning on the low-side FET. Turning on the low-side FET beyond the zero inductor current quickly discharges the output capacitor thus causing the output voltage to fall quickly toward the setpoint. During the operation, the cycle-by cycle negative current limit is also activated to ensure the safe operation of the internal FETs.

7.3.10 UVLO Protection

Under voltage lock out protection (UVLO) monitors the internal VREG5 regulator voltage. When the VREG5 voltage is lower than UVLO threshold voltage, the device is shut off. This protection is non-latching.

7.3.11 Thermal Shutdown

The device monitors the internal die temperature. If this temperature exceeds the thermal shutdown threshold value (T_{SDN} typically 160°C) the device shuts off. This is a non-latch protection. During start up, if the device temperature is higher than 160°C the device does not start switching and does not load the MODE settings. If the device temp goes higher than T_{SDN} threshold after startup, it stops switching with SS reset to ground and an internal discharge switch turns on to quickly discharge the output voltage. The device re-starts switching when the temperature goes below the thermal shutdown threshold but the MODE settings are not re-loaded again. There is a second higher thermal protection on the device $T_{SDN\ VREG5}$ which protects it from over temperature conditions not caused by the switching of the device itself. This threshold is at typically 170°C. Even under nonswitching condition of the device after exceeding T_{SDN} threshold, if it still continues to heat up the VREG5 output shuts off once temperature goes beyond $T_{SDN\ VREG5}$, thereby shutting down the device completely.

7.3.12 Output Voltage Discharge

The device has a 500ohm discharge switch that discharges the output V_{OUT} through SW node during any event of fault like output overvoltage, output undervoltage , TSD , if VREG5 voltage below the UVLO and when the EN pin voltage (V_{EN}) is below the turn-on threshold.

7.4 Device Functional Modes

7.4.1 Light Load Operation

When the MODE pin is selected to operate in FCCM mode, the converter operates in continuous conduction mode (FCCM) during light-load conditions. During FCCM, the switching frequency (F_{SW}) is maintained at an almost constant level over the entire load range which is suitable for applications requiring tight control of the switching frequency and output voltage ripple at the cost of lower efficiency under light load. If the MODE pin is selected to operate in OOA, the device enters pulse skip mode after the valley of the inductor ripple current crosses zero. The OOA mode maintains higher efficiency at light load with a lower switching frequency but this switching frequency is restricted to not go below 25kHz typical.

7.4.2 Standby Operation

The TPS568215OA can be placed in standby mode by pulling the EN pin low. The device operates with a shutdown current of 7uA when in standby condition.

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8 Application and Implementation

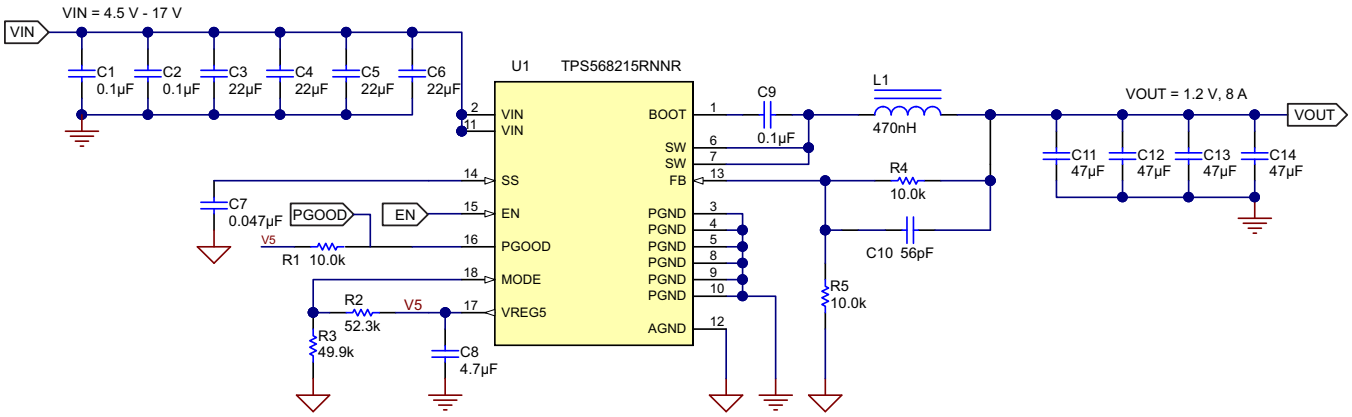
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Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The schematic of 图 22 shows a typical application for TPS568215OA. This design converts an input voltage range of 4.5 V to 17 V down to 1.2 V with a maximum output current of 10 A.

8.2 Typical Application



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图 22. Application Schematic

8.2.1 Design Requirements

表 4. Design Parameters

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT
V_{OUT}	Output voltage			1.2		V
I_{OUT}	Output current			10		A
ΔV_{OUT}	Transient response	4-A load step		±30		mV
V_{IN}	Input voltage		4.5	12	17	V
$V_{OUT(ripple)}$	Output voltage ripple			<10		$mV_{(P-P)}$
	Start input voltage	Input voltage rising		Internal UVLO		V
	Stop input voltage	Input voltage falling		Internal UVLO		V
f_{SW}	Switching frequency			1.2		MHz
Operating Mode				OOA		
T_A	Ambient temperature			25		°C

8.2.2 Detailed Design Procedure

8.2.2.1 External Component Selection

8.2.2.1.1 Output Voltage Set Point

To change the output voltage of the application, it is necessary to change the value of the upper feedback resistor. By changing this resistor the user can change the output voltage above 0.6 V. See 公式 5

$$V_{OUT} = 0.6 \times \left(1 + \frac{R_{UPPER}}{R_{LOWER}}\right) \quad (5)$$

8.2.2.1.2 Switching Frequency and Mode Selection

Switching Frequency, current limit and switching mode (OOA or FCCM) are set by a voltage divider from VREG5 to GND connected to the MODE pin. See 表 3 for possible MODE pin configurations. Switching frequency selection is a tradeoff between higher efficiency and smaller system solution size. Lower switching frequency yields higher overall efficiency but relatively bigger external components. Higher switching frequencies cause additional switching losses which impact efficiency and thermal performance. For this design 1.2 MHz is chosen as the switching frequency, the switching mode is OOA and the output current is 8 A.

8.2.2.1.3 Inductor Selection

The inductor ripple current is filtered by the output capacitor. A higher inductor ripple current means the output capacitor should have a ripple current rating higher than the inductor ripple current. See 表 5 for recommended inductor values.

The RMS and peak currents through the inductor can be calculated using 公式 6 and 公式 7. It is important that the inductor is rated to handle these currents.

$$I_{L(rms)} = \sqrt{I^2_{OUT} + \frac{1}{12} \times \left(\frac{V_{OUT} \times \left(V_{IN(max)} - V_{OUT}\right)}{V_{IN(max)} \times L_{OUT} \times F_{SW}}\right)^2} \quad (6)$$

$$I_{L(peak)} = I_{OUT} + \frac{I_{OUT(ripple)}}{2} \quad (7)$$

During transient/short circuit conditions the inductor current can increase up to the current limit of the device so it is safe to choose an inductor with a saturation current higher than the peak current under current limit condition.

8.2.2.1.4 Output Capacitor Selection

After selecting the inductor the output capacitor needs to be optimized. In DCAP3, the regulator reacts within one cycle to the change in the duty cycle so the good transient performance can be achieved without needing large amounts of output capacitance. The recommended output capacitance range is given in 表 5

Ceramic capacitors have very low ESR, otherwise the maximum ESR of the capacitor should be less than $V_{OUT(ripple)}/I_{OUT(ripple)}$

表 5. Recommended Component Values

V_{OUT} (V)	R_{LOWER} (kΩ)	R_{UPPER} (kΩ)	F_{SW} (kHz)	L_{OUT} (µH)	$C_{OUT(min)}$ (µF)	$C_{OUT(max)}$ (µF)	C_{FF} (pF)
0.6	10	0	400	0.68	300	500	–
			800	0.47	100	500	–
			1200	0.33	88	500	–
1.2		10	400	1.2	100	500	–
			800	0.68	88	500	–
			1200	0.47	88	500	–
3.3		45.3	400	2.4	88	500	100–220
			800	1.5	88	500	100–220
			1200	1.1	88	500	100–220

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表 5. Recommended Component Values (接下页)

V_{OUT} (V)	R_{LOWER} (kΩ)	R_{UPPER} (kΩ)	F_{SW} (kHz)	L_{OUT} (µH)	$C_{OUT(min)}$ (µF)	$C_{OUT(max)}$ (µF)	C_{FF} (pF)
5.5		82.5	400	3.3	88	500	100–220
			800	2.4	88	500	100–220
			1200	1.2	88	700	100–220

8.2.2.1.5 Input Capacitor Selection

The minimum input capacitance required is given in 公式 8.

$$C_{IN(min)} = \frac{I_{OUT} \times V_{OUT}}{V_{INripple} \times V_{IN} \times F_{SW}} \quad (8)$$

TI recommends using a high quality X5R or X7R input decoupling capacitors of 40 µF on the input voltage pin. The voltage rating on the input capacitor must be greater than the maximum input voltage. The capacitor must also have a ripple current rating greater than the maximum input current ripple of the application. The input ripple current is calculated by 公式 9 below:

$$I_{CIN(rms)} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{IN(min)}} \times \frac{(V_{IN(min)} - V_{OUT})}{V_{IN(min)}}} \quad (9)$$

8.2.3 Application Curves

图 23 through 图 39 apply to the circuit of 图 22. V_{IN} = 12 V. T_a = 25 °C unless otherwise specified.

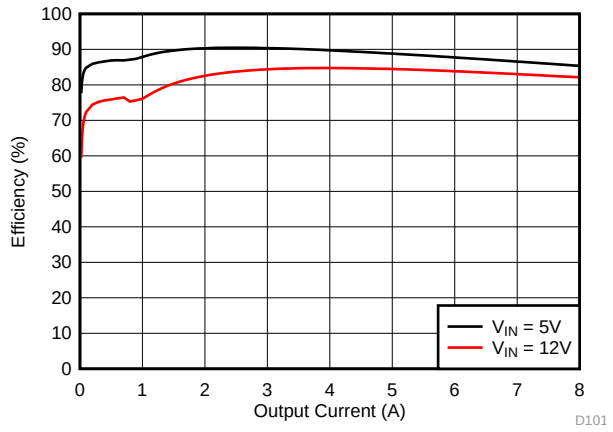


图 23. Efficiency

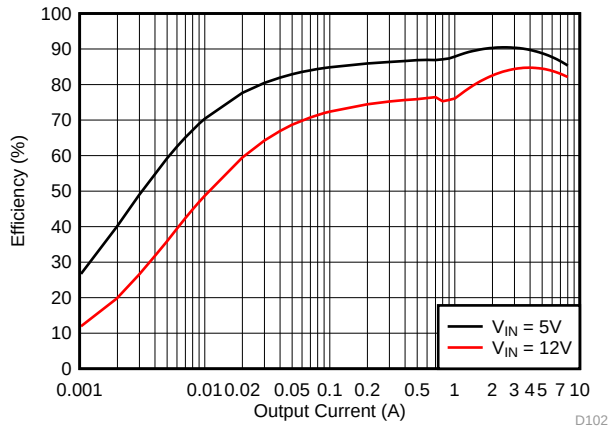


图 24. Light Load Efficiency

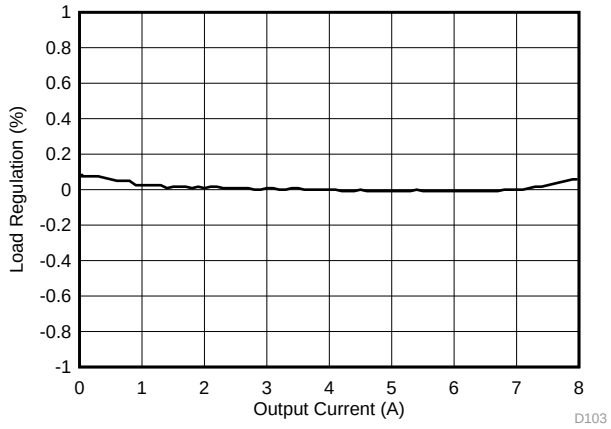


图 25. Load Regulation, V_{IN} = 5 V

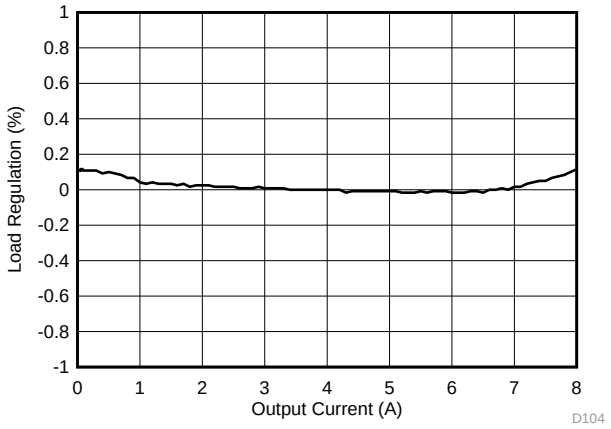


图 26. Load Regulation, V_{IN} = 12 V

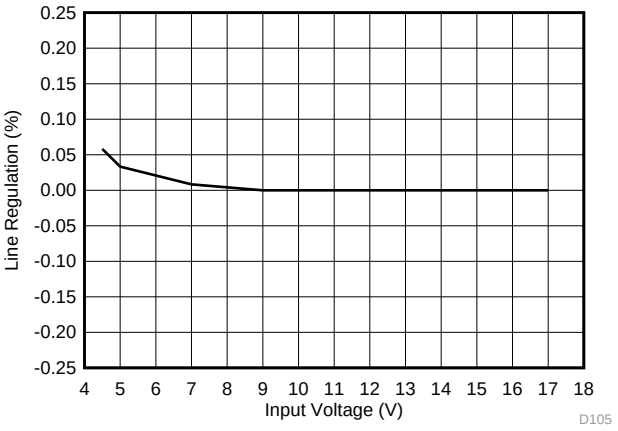


图 27. Line Regulation, I_{OUT} = 6 A

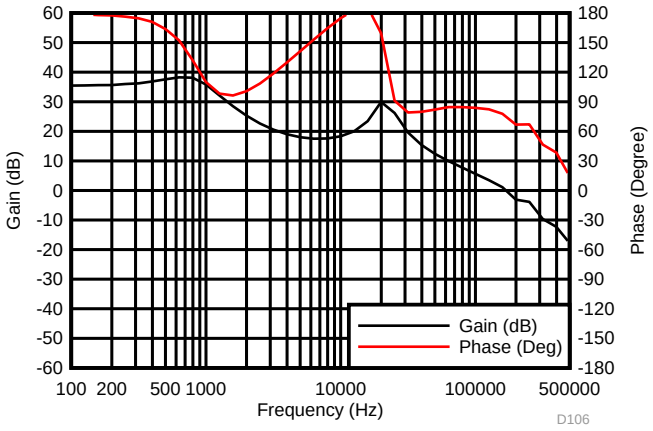


图 28. Loop Response, I_{OUT} = 6 A

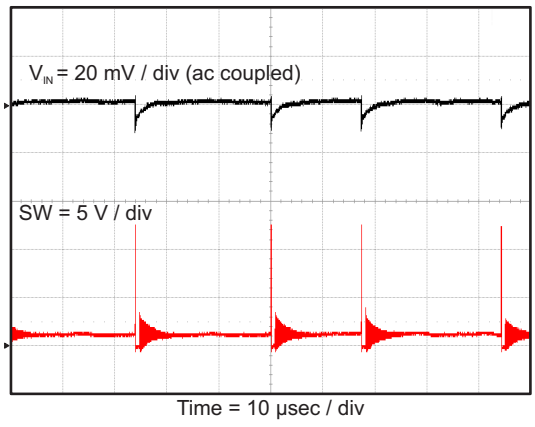


图 29. Input Voltage Ripple, I_{OUT} = 10 mA

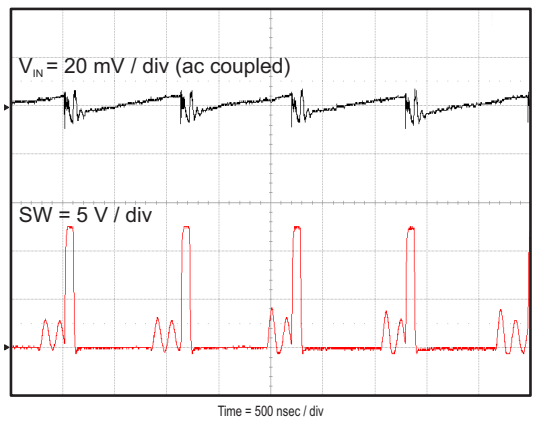


图 30. Input Voltage Ripple, I_{OUT} = 700 mA

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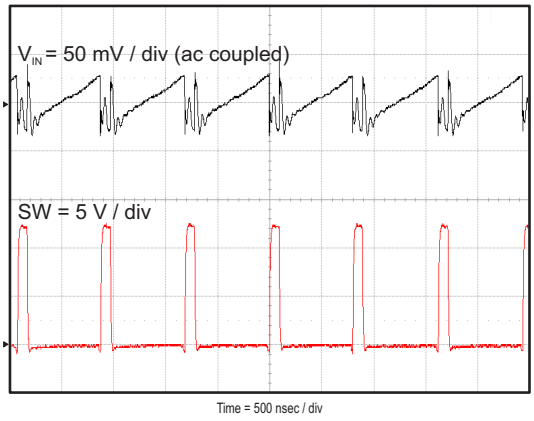


图 31. Input Voltage Ripple, I_{OUT} = 8 A

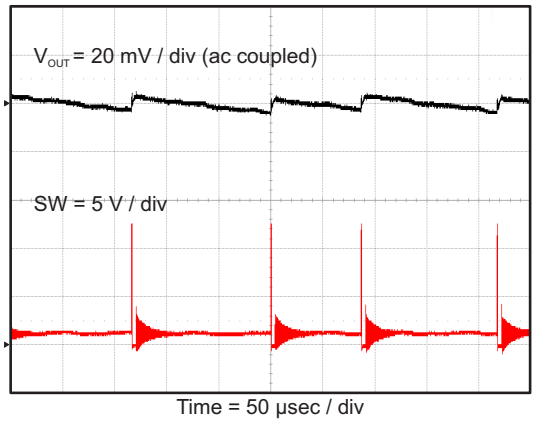


图 32. Output Voltage Ripple, I_{OUT} = 10 mA

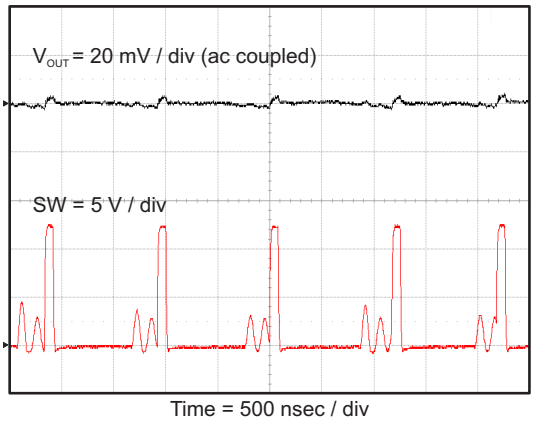


图 33. Output Voltage Ripple, I_{OUT} = 700 mA

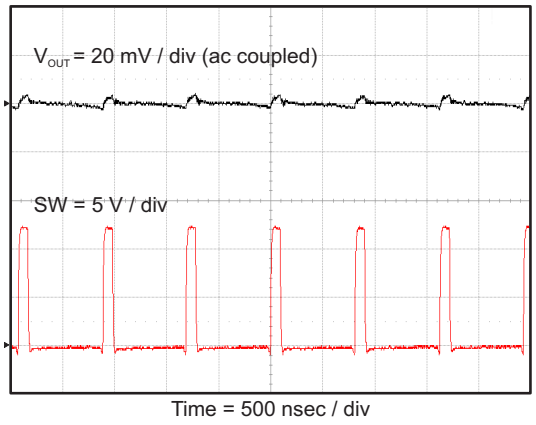


图 34. Output Voltage Ripple, I_{OUT} = 8 A

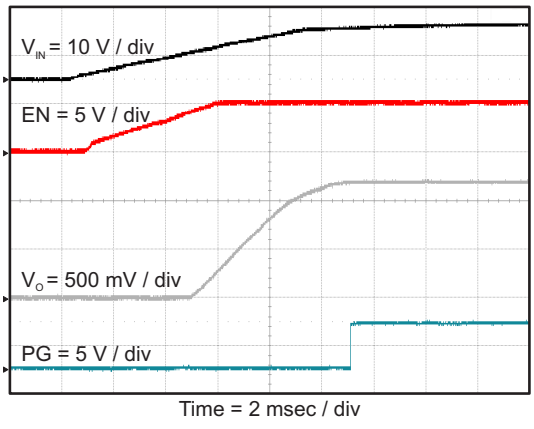


图 35. Start Up Relative to V_{IN} Rising

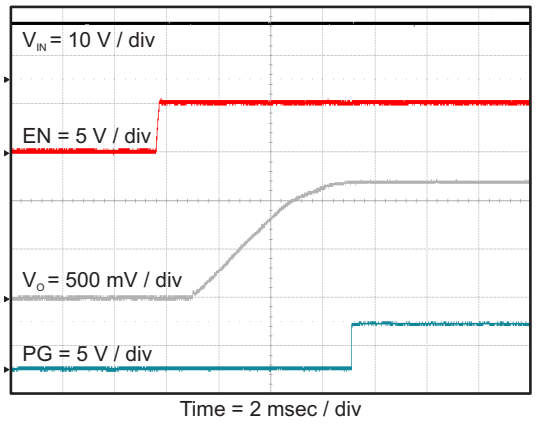


图 36. Start Up Relative to EN Rising

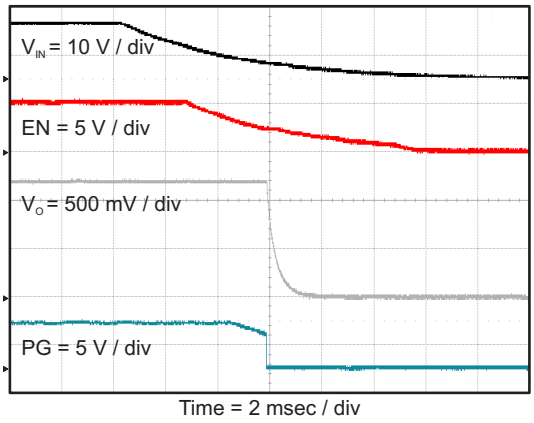


图 37. Shut Down Relative to V_{IN} Falling

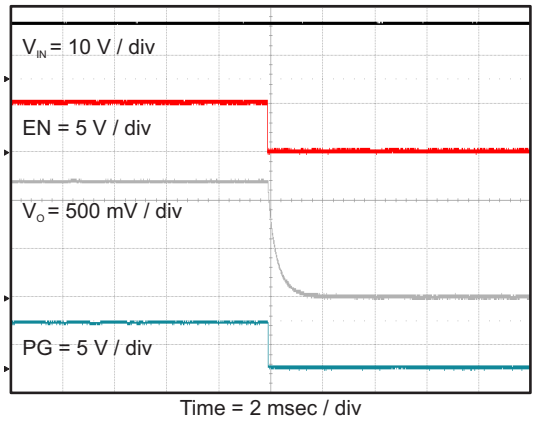


图 38. Shut Down Relative to EN Falling

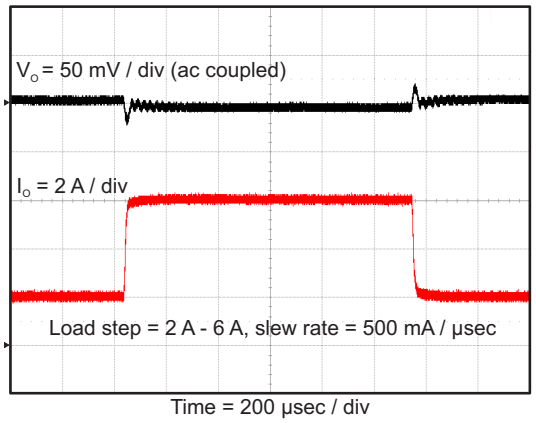


图 39. Transient Response

9 Power Supply Recommendations

The TPS568215OA is intended to be powered by a well regulated dc voltage. The input voltage range is 4.5 to 17 V. TPS568215OA is a buck converter. The input supply voltage must be greater than the desired output voltage for proper operation. Input supply current must be appropriate for the desired output current. If the input voltage supply is located far from the TPS568215OA circuit, some additional input bulk capacitance is recommended. Typical values are 100 µF to 470 µF.

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10 Layout

10.1 Layout Guidelines

- Recommend a four-layer or six-layer PCB for good thermal performance and with maximum ground plane. 3" x 3", four-layer PCB with 2-oz. copper used as example.
- Recommend having equal caps on each side of the IC. Place them right across VIN as close as possible.
- Inner layer 1 will be ground with the PGND to AGND net tie
- Inner layer2 has VIN copper pour that has vias to the top layer VIN. **Place multiple vias under the device near VIN and GND and near input capacitors** to reduce parasitic inductance and improve thermal performance
- Bottom later is GND with the BOOT trace routing.
- Feedback should be referenced to the quite AGND and routed away from the switch node.
- VIN trace must be wide to reduce the trace impedance.

10.2 Layout Example

图 40 shows the recommended top side layout. Component reference designators are the same as the circuit shown in 图 22. Resistor divider for EN is not used in the circuit of 图 22, but are shown in the layout for reference.

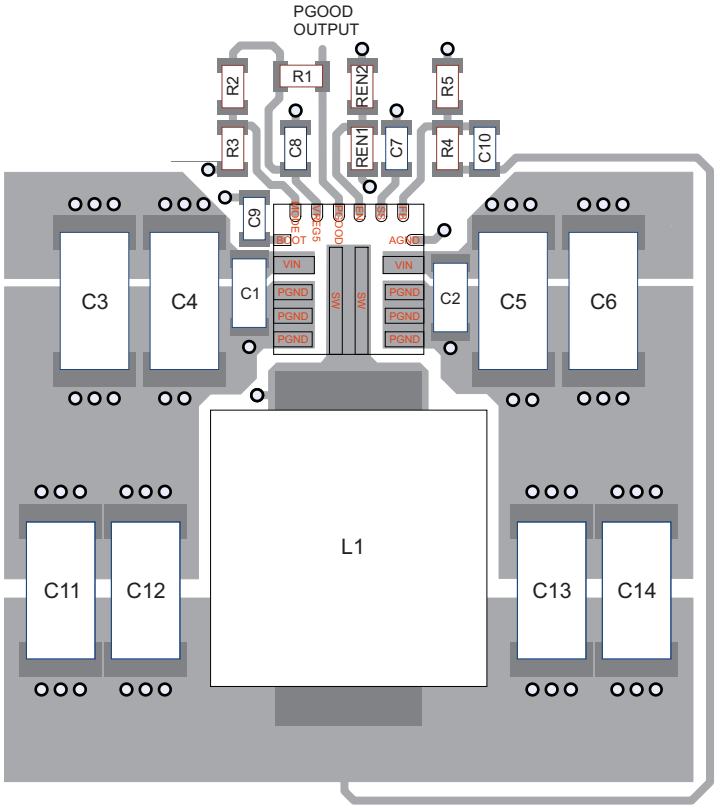


图 40. Top Side Layout

Layout Example (接下页)

图 41 shows the recommended layout for the first internal layer. It is comprised of a large PGND plane and a smaller ANGD island. AGND and PGND are connected at a single point to reduce circulating currents.

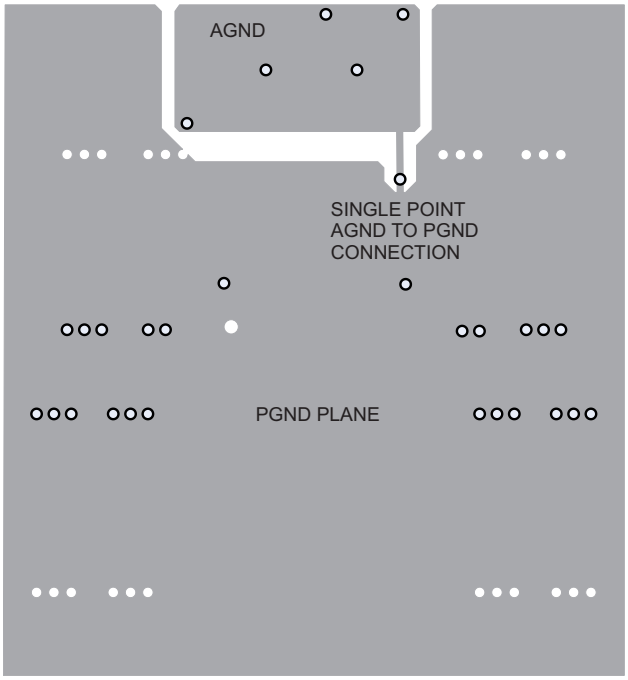


图 41. Mid Layer 1 Layout

图 42 shows the recommended layout for the second internal layer. It is comprised of a large PGND plane, a smaller copper fill area to connect the two top side V_{IN} copper areas and a second V_{OUT} copper fill area.

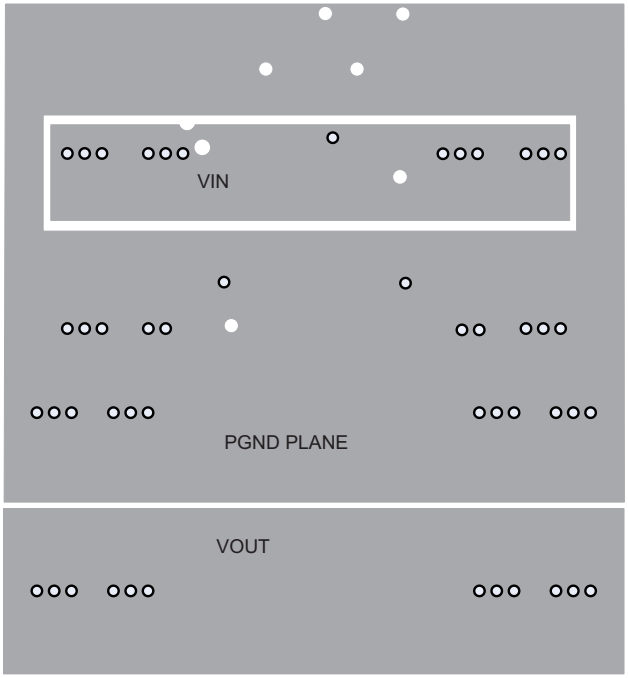


图 42. Mid Layer 2 Layout

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Layout Example (接下页)

图 43 shows the recommended layout for the bottom layer. It is comprised of a large PGND plane and a trace to connect the BOOT capacitor to the SW node.

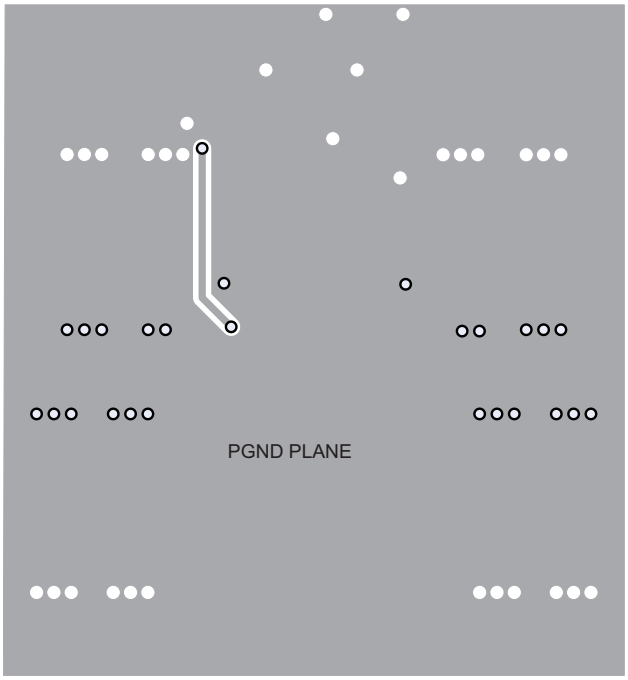


图 43. Bottom Layer Layout

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11 器件和文档支持

11.1 器件支持

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11.1.2 开发支持

- *《TPS568215EVM-762 8A SWIFT™ 稳压器评估模块用户指南》*

11.2 接收文档更新通知

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11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据发生变化时，我们可能不会另行通知或修订此文档。如欲获取此产品说明书的浏览器版本，请参见左侧的导航栏。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS568215OARNNR	Active	Production	VQFN-HR (RNN) | 18	3000 | LARGE T&R	Yes	Call TI | Sn	Level-2-260C-1 YEAR	-40 to 125	215OA
TPS568215OARNNR.A	Active	Production	VQFN-HR (RNN) | 18	3000 | LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	215OA
TPS568215OARNNT	Active	Production	VQFN-HR (RNN) | 18	250 | SMALL T&R	Yes	Call TI | Sn	Level-2-260C-1 YEAR	-40 to 125	215OA
TPS568215OARNNT.A	Active	Production	VQFN-HR (RNN) | 18	250 | SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	215OA

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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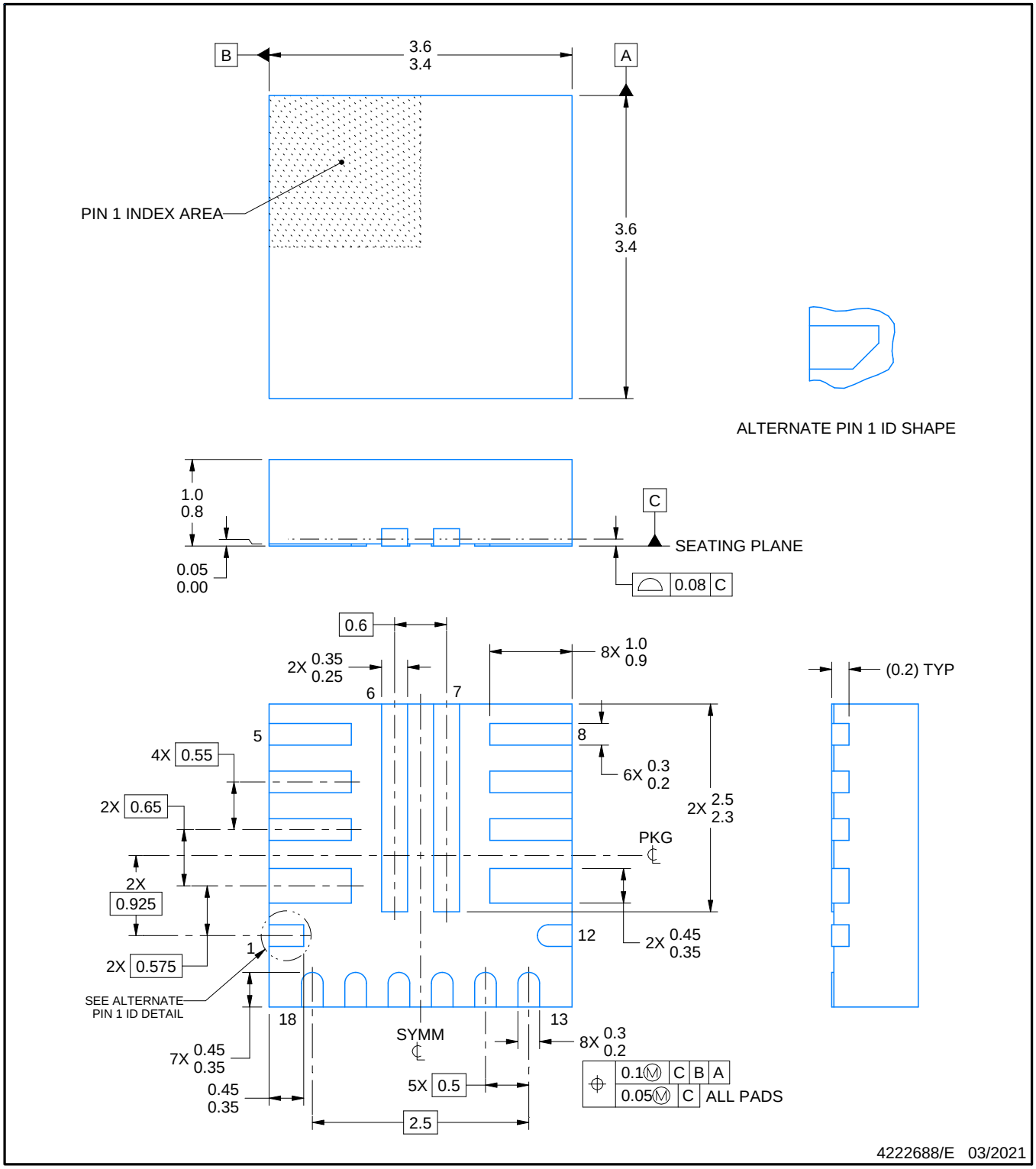
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE OUTLINE

RNN0018A

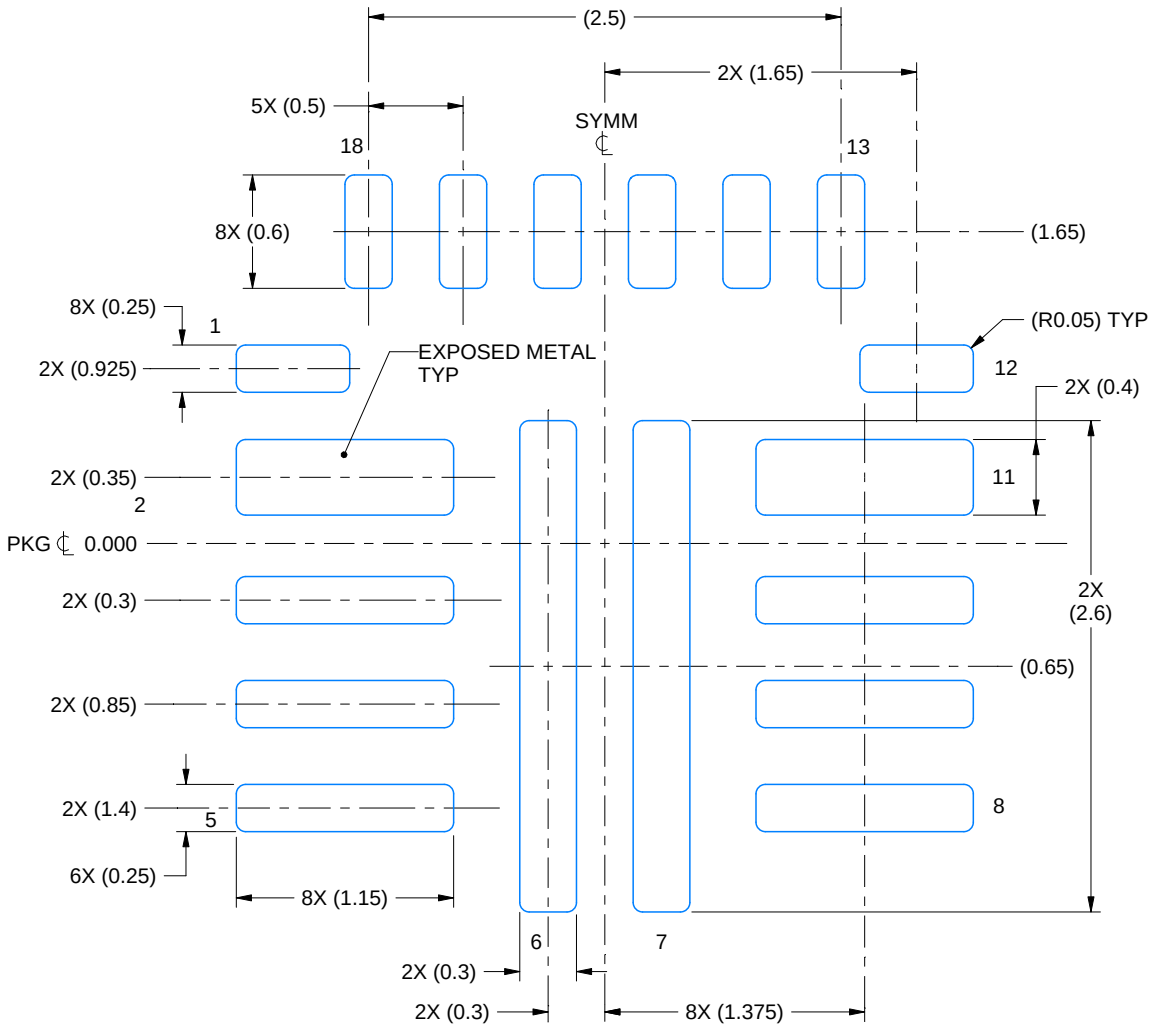
VQFN-HR - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

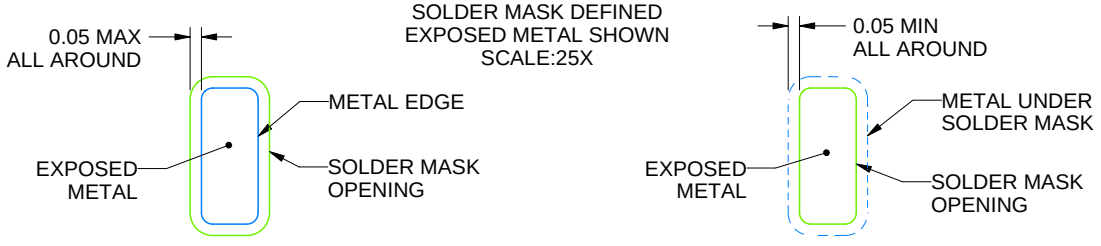


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
SOLDER MASK DEFINED
EXPOSED METAL SHOWN
SCALE:25X



NON SOLDER MASK DEFINED (PREFERRED)

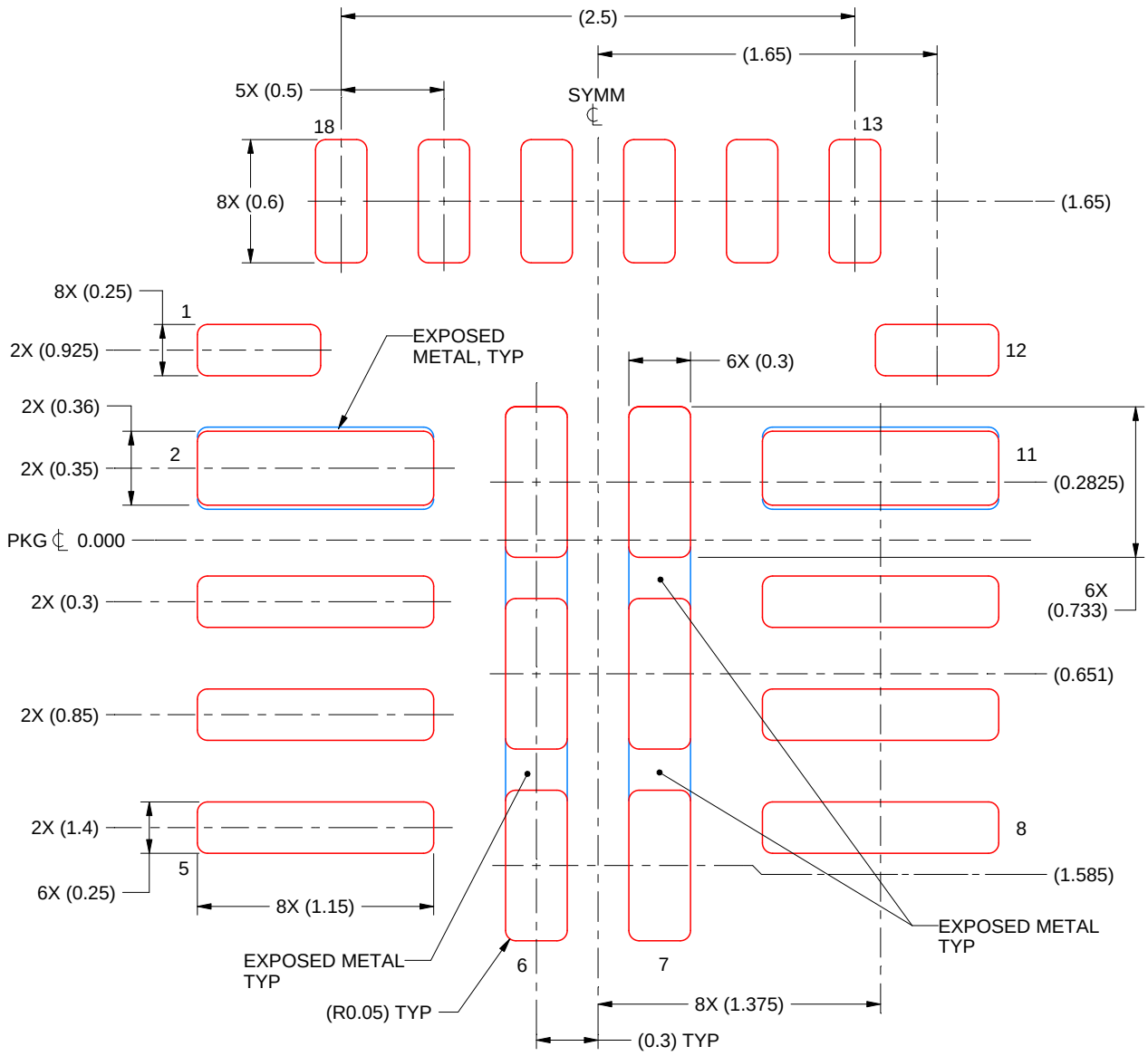
SOLDER MASK DEFINED

SOLDER MASK DETAILS

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NOTES: (continued)

3. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
PADS 6 & 7: 83% - PADS 2 & 11: 90%
SCALE:30X

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NOTES: (continued)

5. For alternate stencil design recommendations, see IPC-7525 or board assembly site preference.

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